

# isc N-Channel MOSFET Transistor

## **IRF1404S**

### • FEATURES

- With TO-263( D2PAK ) packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



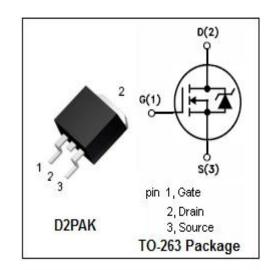
- Power supply
- · Switching applications

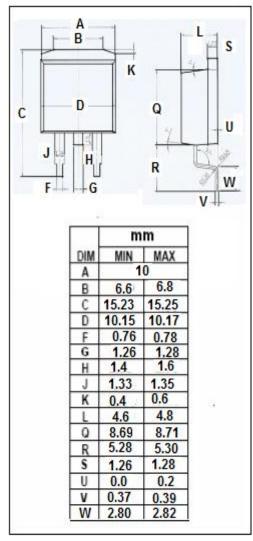


SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	40	V
$V_{GSS}$	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous;Tc=25℃ Tc=100℃	162 115	А
I <sub>DM</sub>	Drain Current-Single Pulsed	650	А
$P_D$	Total Dissipation	200	W
Tj	Operating Junction Temperature	175	${\mathbb C}$
T <sub>stg</sub>	Storage Temperature	-55~175	${\mathbb C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT			
Rth(ch-c)	Channel-to-case thermal resistance 0.75		°C/W			
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W			





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	40			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =95A		3.5	4	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V;V <sub>DS</sub> = 0V			±0.2	μ <b>A</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =40V; V <sub>GS</sub> = 0V;Tc=25°C V <sub>DS</sub> =32V; V <sub>GS</sub> = 0V; Tc=150°C			20 250	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =95A, V <sub>GS</sub> = 0 V			1.3	V

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